

L Number	Hits	Search Text	DB	Time stamp
1	22442	semiconductor and (tft or (thin adj film adj transistor))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/04/01 10:46
2	2038	(semiconductor and (tft or (thin adj film adj transistor))) and gate and drain and source and offset	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/04/01 10:47
3	299	((semiconductor and (tft or (thin adj film adj transistor))) and gate and drain and source and offset) and sidewall	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/04/01 10:48
4	218	((semiconductor and (tft or (thin adj film adj transistor))) and gate and drain and source and offset) and sidewall) and (gate adj electrode)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/04/01 10:49
5	73	((((semiconductor and (tft or (thin adj film adj transistor))) and gate and drain and source and offset) and sidewall) and (gate adj electrode)) and (offset adj region)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/04/01 10:50

L Number	Hits	Search Text	DB	Time stamp
1	6068	(257/57, 59, 66, 72, 347, 350, 329, 330, "331").CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2003/04/01 14:11